

BF246,A,B,C

CASE 29-02, STYLE 22
TO-92 (TO-226AA)

BF247,A,B,C

CASE 29-02, STYLE 5
TO-92 (TO-226AA)

JFET
SWITCHING

N-CHANNEL - DEPLETION

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	±25	Vdc
Drain-Gate Voltage	V _{DG}	25	Vdc
Gate-Source Voltage	V _{GS}	25	Vdc
Drain Current	I _D	100	mAdc
Forward Gate Current	I _{G(f)}	10	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	360 2.88	mW mW/°C
Storage Channel Temperature Range	T _{tsg}	-65 to +150	°C

Refer to MPF4391 for graphs.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

6

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Gate-Source Breakdown Voltage (I _G = 1 μA, V _{DS} = 0)	V(BR)GSS	25	—	—	V
Gate-Source (V _{DS} = 15 V, I _D = 200 μA) BF246, BF247 BF246A, BF247A BF246B, BF247B BF246C, BF247C	V _{GS}	0.5 1.5 3 5.5	— — — —	14 4 7 12	V
Gate-Source Cutoff Voltage (V _{DS} = 15 V, I _D = 10 nA)	V _{GS(off)}	0.6	—	14.5	V
Gate Cutoff Current (V _{GS} = 15 V, V _{DS} = 0)	I _{GSS}	—	—	5	nA
ON CHARACTERISTICS					
Zero-Gate Voltage Drain Current (V _{DS} = 15 V, V _{GS} = 0) BF246, BF247 BF246A, BF247A BF246B, BF247B BF246C, BF247C	I _{DS}	30 30 60 110	—	250 80 140 250	mA

SMALL-SIGNAL CHARACTERISTICS

Forward Transfer Admittance (V _{DS} = 15 V, I _D = 10 mA, f = 1 kHz)	Y _{fs}	8	23		mmhos
Reverse Transfer Capacitance (V _{DS} = 15 V, I _D = 10 mA, f = 1 kHz)	C _{rss}		3.3		pF
Input Capacitance (V _{DS} = 15 V, I _D = 10 mA, f = 1 MHz)	C _{in}		6		pF
Output Capacitance (V _{DS} = 15 V, I _D = 10 mA, f = 1 MHz)	C _{out}		5		pF
Cutoff Frequency (V _{DS} = 15 V, V _{GS} = 0)	F(Y _{fs})		450		MHz